

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (L²-π-MOSV)

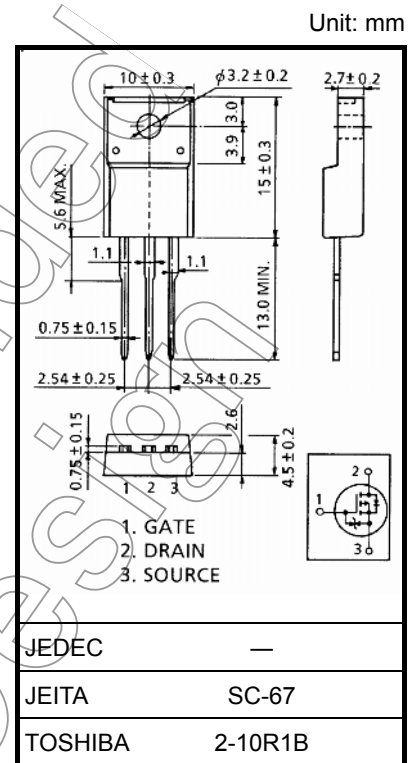
2SJ380

Relay Drive, DC-DC Converter and Motor Drive Applications

- 4-V gate drive
- Low drain-source ON resistance: $R_{DS(ON)} = 0.15 \Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 7.7 S$ (typ.)
- Low leakage current: $I_{DSS} = -100 \mu A$ (max) ($V_{DS} = -100 V$)
- Enhancement mode: $V_{th} = -0.8$ to $-2.0 V$ ($V_{DS} = -10 V, I_D = -1 mA$)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	-100	V
Drain-gate voltage ($R_{GS} = 20 k\Omega$)	V_{DGR}	-100	V
Gate-source voltage	V_{GSS}	± 20	V
Drain current	DC (Note 1)	I_D	-12
	Pulse (Note 1)	I_{DP}	-48
Drain power dissipation ($T_c = 25^\circ C$)	P_D	35	W
Single pulse avalanche energy (Note 2)	E_{AS}	312	mJ
Avalanche current	I_{AR}	-12	A
Repetitive avalanche energy (Note 3)	E_{AR}	3.5	mJ
Channel temperature	T_{ch}	150	°C
Storage temperature range	T_{stg}	-55 to 150	°C



Weight: 1.9 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	$R_{th(ch-c)}$	3.57	°C/W
Thermal resistance, channel to ambient	$R_{th(ch-a)}$	62.5	°C/W

Note1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = -25 V, T_{ch} = 25^\circ C$ (initial), $L = 2.94 mH, R_G = 25 \Omega, I_{AR} = -12 A$

Note 3: Repetitive rating: pulse width limited by maximum junction temperature

This transistor is an electrostatic-sensitive device. Handle with care.

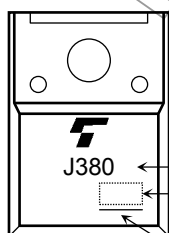
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	$V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 10	μA
Drain cut-off current		I_{DSS}	$V_{DS} = -100\text{ V}, V_{GS} = 0\text{ V}$	—	—	-100	μA
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = -10\text{ mA}, V_{GS} = 0\text{ V}$	-100	—	—	V
Gate threshold voltage		V_{th}	$V_{DS} = -10\text{ V}, I_D = -1\text{ mA}$	-0.8	—	-2.0	V
Drain-source ON resistance		$R_{DS(ON)}$	$V_{GS} = -4\text{ V}, I_D = -6\text{ A}$	—	0.25	0.32	Ω
			$V_{GS} = -10\text{ V}, I_D = -6\text{ A}$	—	0.15	0.21	
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = -10\text{ V}, I_D = -6\text{ A}$	4.5	7.7	—	S
Input capacitance		C_{iss}	$V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	1100	—	pF
Reverse transfer capacitance		C_{rss}		—	200	—	pF
Output capacitance		C_{oss}		—	440	—	pF
Switching time	Rise time	t_r		—	18	—	ns
	Turn-on time	t_{on}		—	30	—	
	Fall time	t_f		—	18	—	
	Turn-off time	t_{off}		—	65	—	
Total gate charge (gate-source plus gate-drain)		Q_g	$V_{DD} \approx -80\text{ V}, V_{GS} = -10\text{ V}, I_D = -12\text{ A}$	—	48	—	nC
Gate-source charge		Q_{gs}		—	29	—	nC
Gate-drain ("miller") charge		Q_{gd}		—	19	—	nC

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	I_{DR}	—	—	—	-12	A
Pulse drain reverse current (Note 1)	I_{DRP}	—	—	—	-48	A
Forward voltage (diode)	V_{DSF}	$I_{DR} = -12\text{ A}, V_{GS} = 0\text{ V}$	—	—	1.7	V
Reverse recovery time	t_{rr}	$I_{DR} = -12\text{ A}, V_{GS} = 0\text{ V}$	—	160	—	ns
Reverse recovery charge	Q_{rr}	$dI_{DR}/dt = 50\text{ A}/\mu\text{s}$	—	0.5	—	μC

Marking



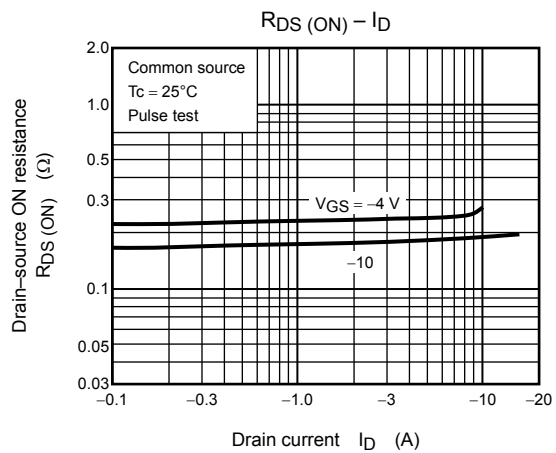
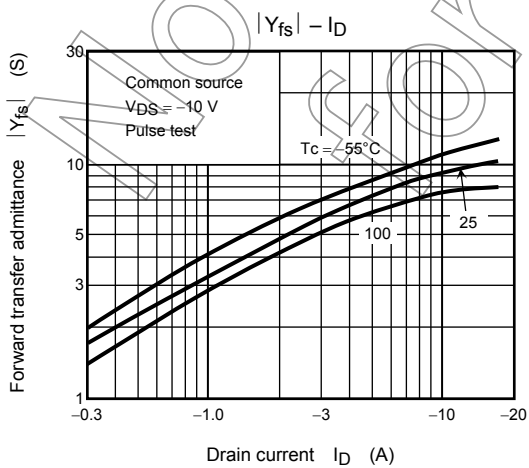
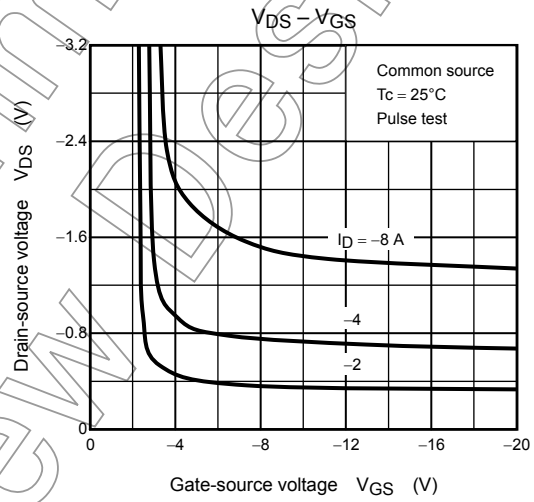
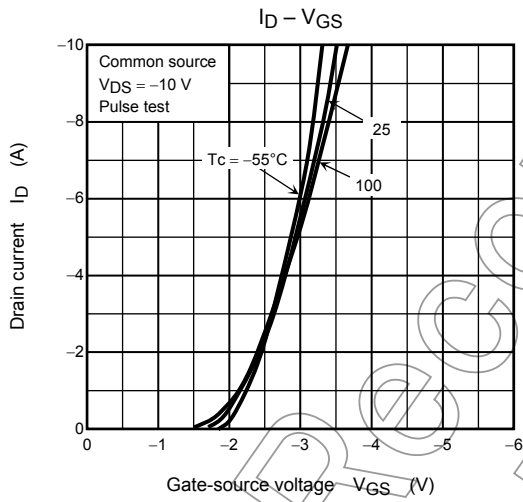
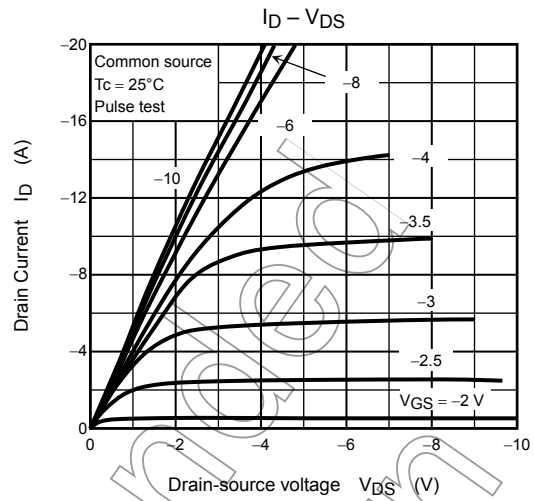
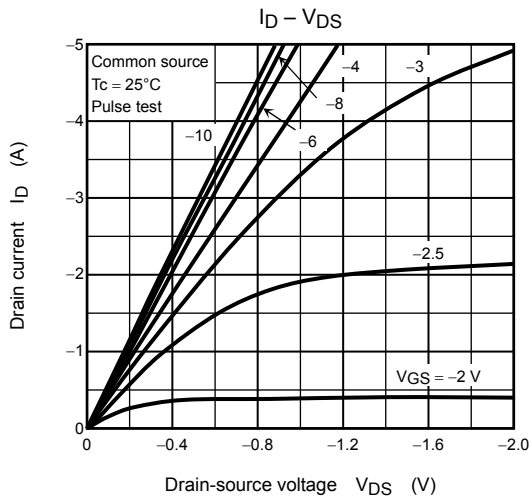
Note 4

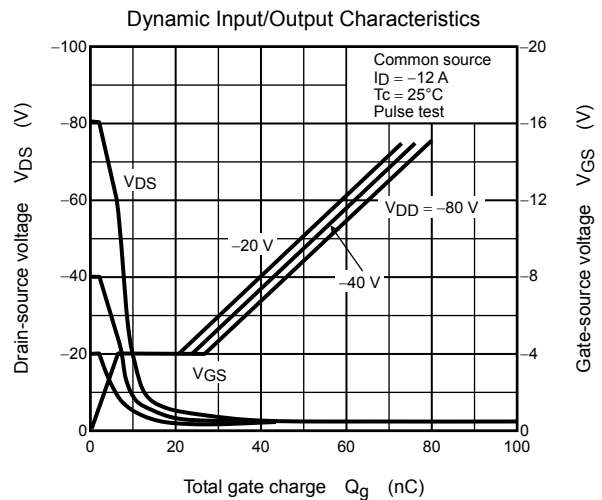
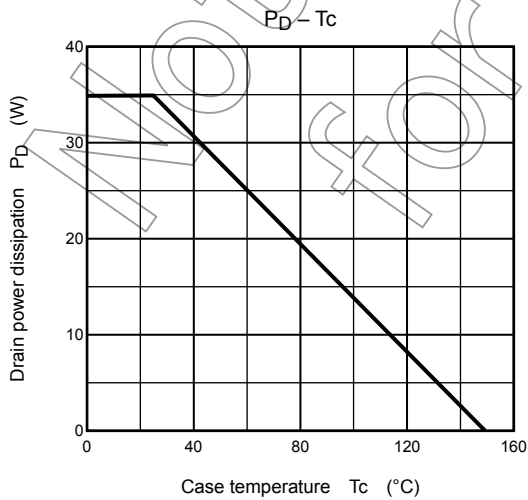
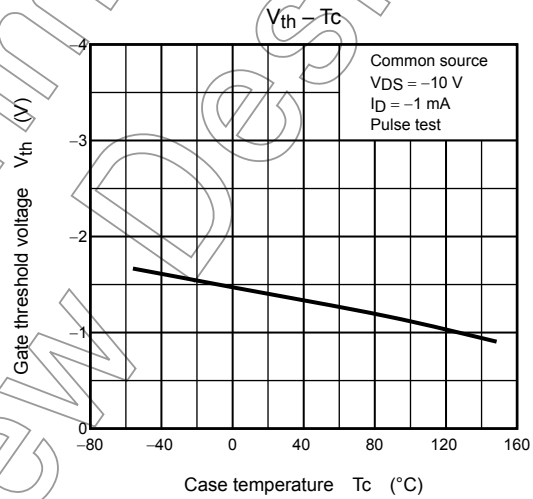
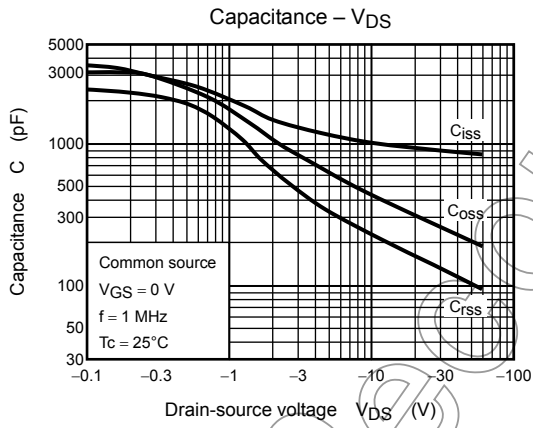
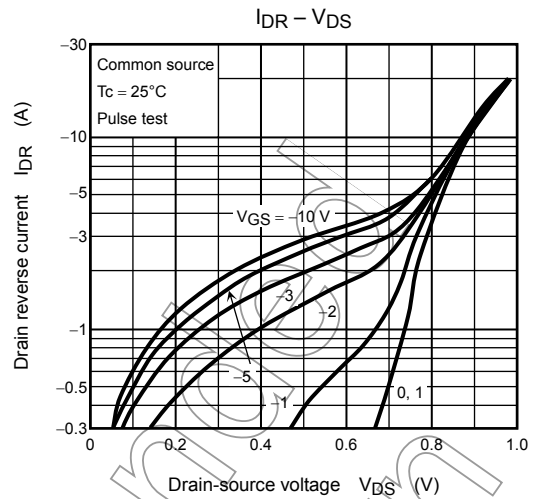
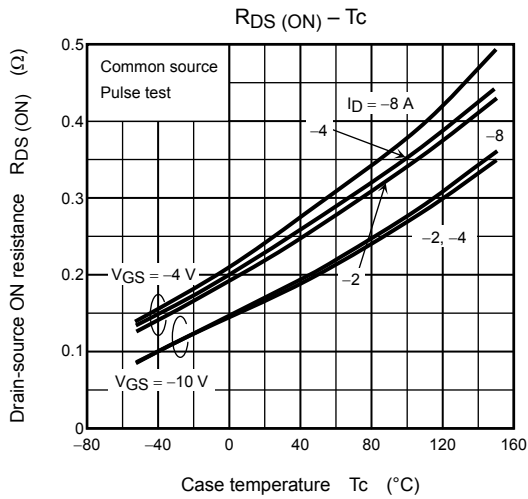
Note 4: A line under a Lot No. identifies the indication of product Labels.

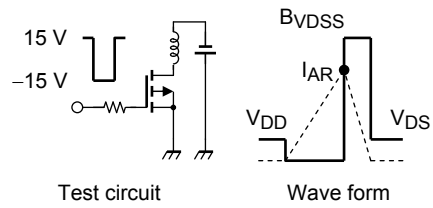
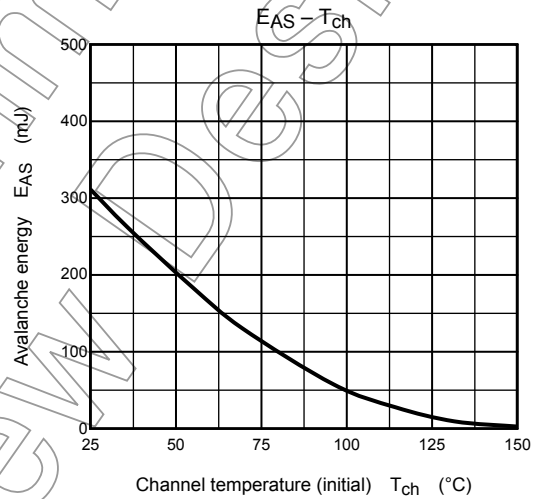
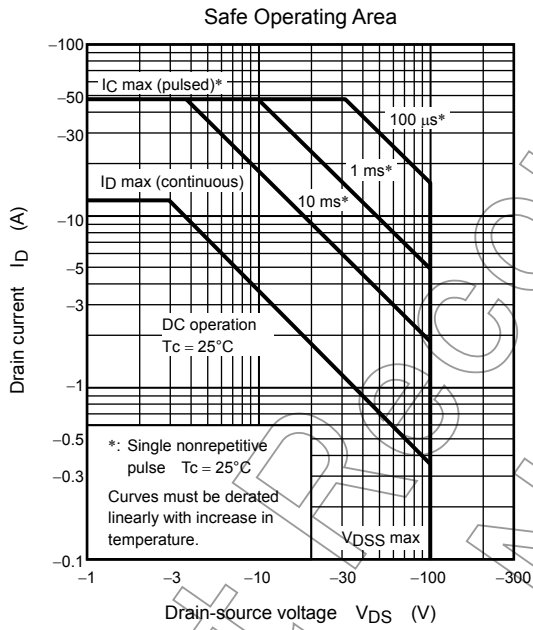
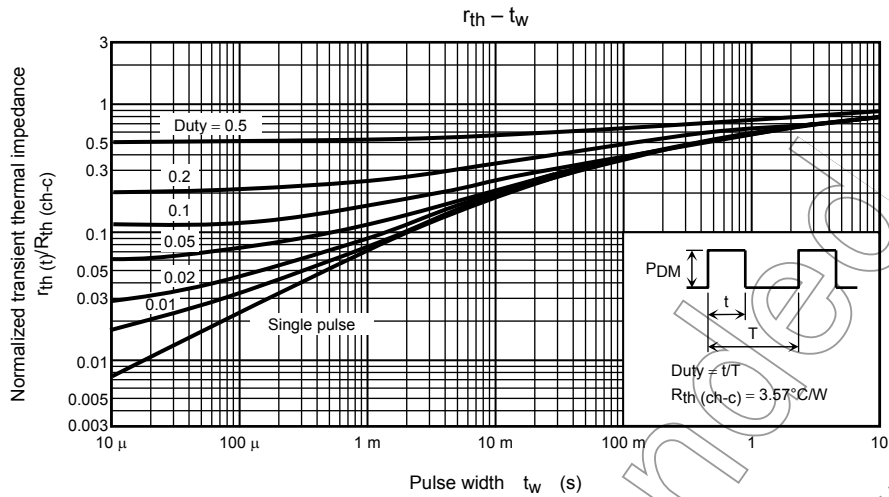
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$R_G = 25 \Omega$
 $V_{DD} = -25 V, L = 2.94 mH$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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